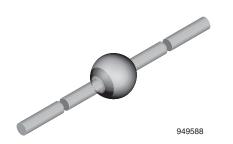


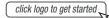
## BYM36A, BYM36B, BYM36C, BYM36D, BYM36E

Vishay Semiconductors

## **Fast Avalanche Sinterglass Diode**



#### **DESIGN SUPPORT TOOLS**





#### **MECHANICAL DATA**

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

Polarity: color band denotes cathode end

Mounting position: any Weight: approx. 858 mg

#### **FEATURES**

- Glass passivated
- · Hermetically sealed package
- · Very low switching losses
- Low reverse current
- · High reverse voltage
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

# Ph



COMPLIANT HALOGEN

### **APPLICATIONS**

- Switched mode power supplies
- High-frequency inverter circuits

ORDERING INFORMATION (Example)						
DEVICE NAME	ORDERING CODE	IG CODE TAPED UNITS MINIMUM ORDER QU				
BYM36E	BYM36E-TR	2500 per 10" tape and reel	12 500			
BYM36E	BYM36E-TAP	2500 per ammopack	12 500			

PARTS TABLE					
PART	TYPE DIFFERENTIATION	PACKAGE			
BYM36A	$V_R = 200 \text{ V}; I_{F(AV)} = 3 \text{ A}$	SOD-64			
BYM36B	$V_R = 400 \text{ V}; \ I_{F(AV)} = 3 \text{ A}$	SOD-64			
BYM36C	$V_R = 600 \text{ V}; I_{F(AV)} = 3 \text{ A}$	SOD-64			
BYM36D	$V_R = 800 \text{ V}; I_{F(AV)} = 2.9 \text{ A}$	SOD-64			
BYM36E	$V_R = 1000 \text{ V}; \ I_{F(AV)} = 2.9 \text{ A}$	SOD-64			

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
		BYM36A	$V_R = V_{RRM}$	200	V	
B		BYM36B	$V_R = V_{RRM}$	400	V	
Reverse voltage = repetitive peak reverse voltage	See electrical characteristics	BYM36C	$V_R = V_{RRM}$	600	V	
- repetitive peak reverse voltage		BYM36D	$V_R = V_{RRM}$	800	V	
		BYM36E	$V_R = V_{RRM}$	1000	<b>V</b>	
Peak forward surge current	$t_p = 10 \text{ ms}$ , half sine wave		I <sub>FSM</sub>	65	Α	
		BYM36A	I <sub>F(AV)</sub>	3	Α	
		BYM36B	I <sub>F(AV)</sub>	3	Α	
Average forward current		BYM36C	I <sub>F(AV)</sub>	3	Α	
		BYM36D	I <sub>F(AV)</sub>	2.9	Α	
		BYM36E	I <sub>F(AV)</sub>	2.9	Α	
Non repetitive reverse avalanche energy	I <sub>(BR)R</sub> = 1 A, inductive load		E <sub>R</sub>	20	mJ	
Junction and storage temperature range			$T_j = T_{stg}$	-55 to +175	°C	



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MAXIMUM THERMAL RESISTANCE (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Junction ambient	Lead length I = 10 mm, T <sub>L</sub> = constant	$R_{thJA}$	25	K/W	
Junction ambient	On PC board with spacing 25 mm	$R_{thJA}$	70	K/W	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I <sub>F</sub> = 3 A	BYM36A	$V_{F}$	-	-	1.6	V
		BYM36B	$V_{F}$	-	-	1.6	V
		BYM36C	$V_{F}$	-	-	1.6	V
		BYM36D	$V_{F}$	-	-	1.78	V
Forward voltage		BYM36E	$V_{F}$	-	-	1.78	V
Forward voltage	I <sub>F</sub> = 3 A, T <sub>j</sub> = 175 °C	BYM36A	$V_{F}$	-	-	1.22	V
		BYM36B	$V_{F}$	-	-	1.22	V
		BYM36C	$V_{F}$	-	-	1.22	V
		BYM36D	$V_{F}$	-	-	1.28	V
		BYM36E	$V_{F}$	-	-	1.28	V
Reverse current	$V_R = V_{RRM}$		I <sub>R</sub>	-	-	5	μA
neverse current	V <sub>R</sub> = V <sub>RRM</sub> , T <sub>j</sub> = 150 °C		I <sub>R</sub>	-	-	100	μA
	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, i <sub>R</sub> = 0.25 A	BYM36A	t <sub>rr</sub>	-	-	100	ns
		BYM36B	t <sub>rr</sub>	-	-	100	ns
Reverse recovery time		BYM36C	t <sub>rr</sub>	-	-	100	ns
		BYM36D	t <sub>rr</sub>	-	-	150	ns
		BYM36E	t <sub>rr</sub>	-	-	150	ns
	I <sub>R</sub> = 100 μA	BYM36A	V <sub>(BR)R</sub>	300	-	-	V
		BYM36B	V <sub>(BR)R</sub>	500	-	-	V
Reverse breakdown voltage		BYM36C	V <sub>(BR)R</sub>	700	-	-	V
		BYM36D	V <sub>(BR)R</sub>	900	-	-	V
		BYM36E	V <sub>(BR)R</sub>	1100	-	-	V

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

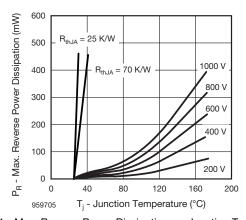


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

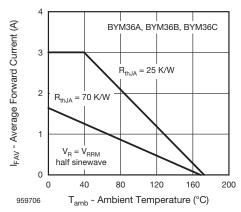


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature

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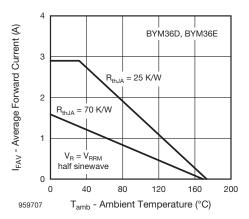


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

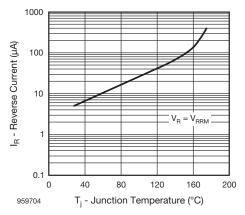


Fig. 4 - Max. Reverse Current vs. Junction Temperature

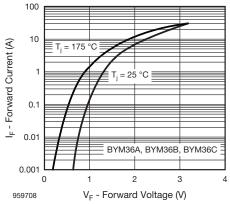


Fig. 5 - Max. Forward Current vs. Forward Voltage

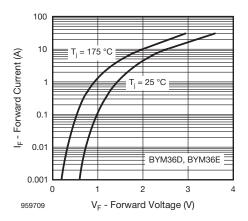


Fig. 6 - Max. Forward Current vs. Forward Voltage

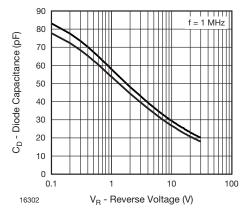


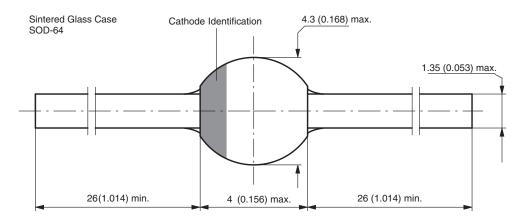
Fig. 7 - Diode Capacitance vs. Reverse Voltage



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## PACKAGE DIMENSIONS in millimeters (inches): SOD-64



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